

### **INCHANGE SEMICONDUCTOR**

## **isc** Silicon NPN Darlington Power Transistor

# 2SD1764

### DESCRIPTION

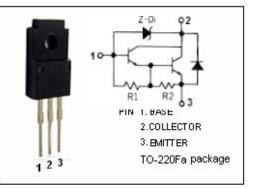
- High DC Current Gain
- : h<sub>FE</sub>= 1000(Min) @I<sub>C</sub>= 1A
- Low Collector Saturation Voltgae-
- :  $V_{CE(sat)}$ = 1.5V(Max.)@ I<sub>C</sub>= 1A
- Bullt-in damper diode
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

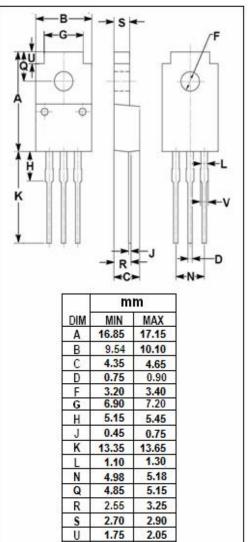
### **APPLICATIONS**

Designed forr Motor, Relay and Solenoid driver applications

### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>сво</sub>	Collector-Base Voltage	50-70	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	50-70	V	
V <sub>EBO</sub>	Emitter-Base Voltage	6	V	
lc	Collector Current-Continuous	2	A	
I <sub>CP</sub>	Collector Current-Peak	3	A	
Pc	Collector Power Dissipation @ $T_a=25^{\circ}C$	2	W	
	Collector Power Dissipation @ $T_c=25^{\circ}C$	20		
TJ	Junction Temperature	150	°C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	°C	





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1.30

1.50



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### **ELECTRICAL CHARACTERISTICS**

#### $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 5mA; I <sub>B</sub> = 0	50		70	V
V <sub>(BR)CBO</sub>	Collector-Base Breakdown Voltage	I <sub>C</sub> = 0.1mA; I <sub>E</sub> = 0	50		70	V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 1A; I <sub>B</sub> = 1mA			1.5	V
V <sub>BE(sat)</sub>	Base-Emitter Saturation Voltage	I <sub>C</sub> = 1Α; I <sub>B</sub> = 1mΑ			2.0	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 40V; I <sub>E</sub> = 0			1	μ <b>Α</b>
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			3.0	mA
h <sub>FE</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 2V	1000		10000	
Сов	Output Capacitance	I <sub>E</sub> = 0 ; V <sub>CB</sub> = 10V,f <sub>test</sub> = 1MHz		25		pF

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